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- 1862 Near-field optical beam induced current measurements on heterostructures
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- 1865 Growth of germanium-carbon alloys on silicon substrates by molecular beam epitaxy
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- 1868 High-power InGaN single-quantum-well-structure blue and violet light-emitting diodes
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- 1883 Measurement of the minority carrier mobility in the base of heterojunction bipolar transistors using a magnetotransport method
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- 1885 Comparative analysis of the optical quality of single In_{0.1}Ga_{0.9}As/Al_{0.33}Ga_{0.67}As quantum wells grown by molecular beam epitaxy on (100) and (311) GaAs substrates
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- 1888 Photoluminescence and microstructure of self-ordered grown SiGe/Si quantum wires
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- 1891 Eu-doped CaF₂ grown on Si(100) substrates by molecular beam epitaxy
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- 1894 Minority carrier lifetime improvement by gettering in Si_{1-x}Ge_x
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- 1896 Reduction of recombination current in CdTe/CdS solar cells
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- 1899 The electronic structure and energy level alignment of porphyrin/metal interfaces studied by ultraviolet photoelectron spectroscopy
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- 1905 Band filling at low optical power density in semiconductor dots
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- 1908 Investigation of high-field domain formation in tight-binding superlattices by capacitance–voltage measurements
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- 1911 High quality single and double two-dimensional electron gases grown by metalorganic vapor phase epitaxy
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1920 Deposition of high quality $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$ films on ultrathin ($12\ \mu\text{m}$ thick) sapphire substrates for infrared detector applications

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1926 Biomagnetic measurements using low-noise integrated SQUID magnetometers operating in liquid nitrogen

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1929 Correlation of critical current and resistance fluctuations in bicrystal grain boundary Josephson junctions

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1932 Determination of pinning strength of $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ from magnetic stiffness measurements

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1935 Disorder and synchronization in a Josephson junction plaquette

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PAPERS IN OTHER FIELDS

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N. Angert, M. Tseitlin, E. Yashchin, M. Roth

COMMENTS

1944 Comment on "Phase transformation of cobalt induced by ball milling" [Appl. Phys. Lett. 66, 308 (1995)]

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1945 Response to "Comment on 'Phase transformation of cobalt induced by ball milling'" [Appl. Phys. Lett. 67, 1944 (1995)]

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